L Number	Hits	Search Text	DB	Time stamp
1	14350	magnetic near2 memory	USPAT; US-PGPUB; EPO; JPO	2002/10/01 13:43
2	559	mram	USPAT; US-PGPUB; EPO; JPO	2002/10/01 13:30
3	2451392	reference	USPAT; US-PGPUB; EPO; JPO	2002/10/01 13:30
4	5447	ferromagnetic near2 layer	USPAT; US-PGPUB; EPO; JPO	2002/10/01 13:31
5	1802523	compar$5	USPAT; US-PGPUB; EPO; JPO	2002/10/01 13:32
7	40	reference with (magnetic near2 memory) with compar$5	USPAT; US-PGPUB; EPO; JPO	2002/10/01 13:33
8	14598	(magnetic near2 memory) or mram	USPAT; US-PGPUB; EPO; JPO	2002/10/01 13:34
9	50	((magnetic near2 memory) or mram) with reference with compar$5	USPAT; US-PGPUB; EPO; JPO	2002/10/01 13:35
6	4	(magnetic near2 memory) with mram with (ferromagnetic near2 layer)	USPAT; US-PGPUB; EPO; JPO	2002/10/01 13:42
11	2	plurality near2 magnetic near2 tunneling near2 junction	USPAT; US-PGPUB; EPO; JPO	2002/10/01 13:44
10	75	magnetic near2 tunneling near2 junction	USPAT; US-PGPUB; EPO; JPO	2002/10/01 13:58
12	6295	reference adj2 cell	USPAT; US-PGPUB; EPO; JPO	2002/10/01 13:58
13	13	(reference adj2 cell) with ((magnetic near2 memory) or mram)	USPAT; US-PGPUB; EPO; JPO	2002/10/01 13:59

L Number	Hits	Search Text	DB	Time stamp
1	14350	magnetic near2 memory	USPAT; US-PGPUB; EPO; JPO	2002/10/01 13:43
2	559	mram	USPAT; US-PGPUB; EPO; JPO	2002/10/01 13:30
3	2451392	reference	USPAT; US-PGPUB; EPO; JPO	2002/10/01 13:30
4	5447	ferromagnetic near2 layer	USPAT; US-PGPUB; EPO; JPO	2002/10/01 13:31
5	1802523	compar$5	USPAT; US-PGPUB; EPO; JPO	2002/10/01 13:32
7	40	reference with (magnetic near2 memory) with compar$5	USPAT; US-PGPUB; EPO; JPO	2002/10/01 13:33
8	14598	(magnetic near2 memory) or mram	USPAT; US-PGPUB; EPO; JPO	2002/10/01 13:34
9	50	((magnetic near2 memory) or mram) with reference with compar$5	USPAT; US-PGPUB; EPO; JPO	2002/10/01 13:35
6	4	(magnetic near2 memory) with mram with (ferromagnetic near2 layer)	USPAT; US-PGPUB; EPO; JPO	2002/10/01 13:42
11	2	plurality near2 magnetic near2 tunneling near2 junction	USPAT; US-PGPUB; EPO; JPO	2002/10/01 13:44
10	75	magnetic near2 tunneling near2 junction	USPAT; US-PGPUB; EPO; JPO	2002/10/01 13:58
12	6295	reference adj2 cell	USPAT; US-PGPUB; EPO; JPO	2002/10/01 13:58
13	13	(reference adj2 cell) with ((magnetic near2 memory) or mram)	USPAT; US-PGPUB; EPO; JPO	2002/10/01 14:16
15	111871	current near2 source	USPAT; US-PGPUB; EPO; JPO	2002/10/01 15:23
16	17	(current near2 source) with (reference adj2 cell) with compar$5	USPAT; US-PGPUB; EPO; JPO	2002/10/01 15:54
17	27634	writ$3 near2 circuit$3	USPAT; US-PGPUB; EPO; JPO	2002/10/01 15:56
-	559	mram	USPAT; US-PGPUB; EPO; JPO	2002/10/01 13:30
-	14350	magnetic near2 memory	USPAT; US-PGPUB; EPO; JPO	2002/10/01 13:30
-	2451392	reference	USPAT; US-PGPUB; EPO; JPO	2002/10/01 13:30
-	5447	ferromagnetic near2 layer	USPAT; US-PGPUB; EPO; JPO	2002/10/01 13:30
-	1802523	compar$5	USPAT; US-PGPUB; EPO; JPO	2002/10/01 13:30
-	14598	mram or (magnetic near2 memory)	USPAT; US-PGPUB; EPO; JPO	2002/10/01 11:56
-	95	(mram or (magnetic near2 memory)) with (ferromagnetic near2 layer)	USPAT; US-PGPUB; EPO; JPO	2002/10/01 11:56

-	2	compar$5 with ((mram or (magnetic near2 memory)) with (ferromagnetic near2 layer))	USPAT; US-PGPUB; EPO; JPO	2002/10/01 11:58
-	198149	reference with compar$5	USPAT; US-PGPUB; EPO; JPO	2002/10/01 11:59
-	97	(reference with compar$5) same (mram or (magnetic near2 memory))	USPAT; US-PGPUB; EPO; JPO	2002/10/01 11:59